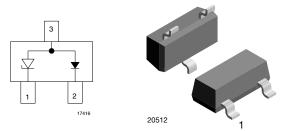


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GL05T to GL24T

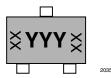
Low Capacitance ESD Protection Diodes for High-Speed Data Interfaces



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MARKING

(example only)



Ε

G

Bar = cathode marking

YYY = type code (see table below)

XX = date code

LINKS TO ADDITIONAL RESOURCES

Н



GL05T-

GL05T-

FEATURES

- IEC 61000-4-5 (lightning) see I_{PPM} below
- ESD immunity acc. IEC 61000-4-2 ± 8 kV contact discharge
 - ± 15 kV air discharge
- ESD capability according to AEC-Q101: human body model: class H3B: > 8 kV
- SOT-23 package
- · Low capacitance for high speed data lines, cellular handsets, USB port protection, LAN equipment, peripherals
- e3 Sn
- AEC-Q101 qualified available
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

-18

-18

GL05T-HE3-18 GL05T-HG3-18





COMPLIANT HALOGEN FREE



ORDERING INFORMATION									
	ENVIR	ONMENTAL AN	ID QUALITY C	ODE	PACKAG	ING CODE			
PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	RoHS-COM LEAD (P	MPLIANT + b)-FREE	TIN PLATED	3K PER 7" REEL (8 mm TAPE),	10K PER 13" REEL (8 mm TAPE),	ORDERING CODE (EXAMPLE)		
(,	QUALIFIED	STANDARD	GREEN	PLATED	15K/BOX = MOQ	10K/BOX = MOQ			
GL05T-		E		3	-08		GL05T-E3-08		
GL05T-			G	3	-08		GL05T-G3-08		
GL05T-	Н	Е		3	-08		GL05T-HE3-08		
GL05T-	Н		G	3	-08		GL05T-HG3-08		
GL05T-		E		3		-18	GL05T-E3-18		
GL05T-			G	3		-18	GL05T-G3-18		

3

PACK	PACKAGE DATA									
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS			
GL05T	SOT-23	L05	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GLOST	301-23	L06	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GL12T	SOT-23	L12	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GLIZI	L13		MSI level 1		MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C				
GL15T	SOT-23	L15	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GLIST	301-23	L16	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GL24T	SOT-23	L24	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			
GLZ41	301-23	L25	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			

Rev. 2.5, 20-May-2021 Document Number: 85809



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GL05T to GL24T

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ABSOLUTE MAXIMUM RATINGS GL05T							
PARAMETER	TEST	CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	8/20 µs	Din 1 2 (nin 2 n a)	I _{PPM}	25	Α		
Peak pulse power	8/20 µs waveform	Pin 1-2 (pin 3 n.c.)	P _{PP}	300	W		
ESD immunity	Contact discharge	acc. IEC 61000-4-2; 10 pulses	V	± 8	kV		
ESD IIIIIIUIIIIY	Air discharge acc. I	IEC 61000-4-2; 10 pulses	V_{ESD}	± 15	kV		
Blocking voltage	I _B = 1 μA	Pin 2-1 or pin 2-3	V _B	70	V		
Operating temperature	Junction temperatu	ire	TJ	-55 to +150	°C		
Storage temperature			T _{STG}	-55 to +150	°C		

ABSOLUTE MAXIMUM RATINGS GL12T									
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT				
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I _{PPM}	12	Α				
Peak pulse power	8/20 µs waveform	Pin 1-2 (pin 3 n.c.)	P _{PP}	300	W				
ESD immunity	Contact discharge	Contact discharge acc. IEC 61000-4-2; 10 pulses		± 8	kV				
ESD illillidnity	Air discharge acc.	IEC 61000-4-2; 10 pulses	V_{ESD}	± 15	kV				
Blocking voltage	$I_B = 1 \mu A$	Pin 2-1 or pin 2-3	V_{B}	70	V				
Operating temperature	Junction temperatu	ıre	T_J	-55 to +150	°C				
Storage temperature			T _{STG}	-55 to +150	°C				

ABSOLUTE MAXIMUM RATINGS GL15T							
PARAMETER	TEST	CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I _{PPM}	10	Α		
Peak pulse power	8/20 µs waveform	Pin 1-2 (pin 3 n.c.)	P _{PP}	300	W		
ESD immunity	Contact discharge	acc. IEC 61000-4-2; 10 pulses	\/	± 8	kV		
ESD IIIIIIIIIIIII	Air discharge acc. I	EC 61000-4-2; 10 pulses	V_{ESD}	± 15	kV		
Blocking voltage	I _B = 1 μA	Pin 2-1 or pin 2-3	V _B	70	V		
Operating temperature	Junction temperatu	ire	T _J	-55 to +150	°C		
Storage temperature			T _{STG}	-55 to +150	°C		

ABSOLUTE MAXIMUM RATINGS GL24T								
PARAMETER	TEST	CONDITIONS	SYMBOL	VALUE	UNIT			
Peak pulse current	8/20 μs	Pin 1-2 (pin 3 n.c.)	I _{PPM}	5	Α			
Peak pulse power	8/20 µs waveform	Fiii 1-2 (βiii 3 ii.c.)	P _{PP}	300	W			
ESD immunity	Contact discharge	acc. IEC 61000-4-2; 10 pulses		± 8	kV			
ESD IIIIIIdility	Air discharge acc. I	EC 61000-4-2; 10 pulses	V_{ESD}	± 15	kV			
Blocking voltage	I _B = 1 μA	Pin 2-1 or pin 2-3	V _B	70	V			
Operating temperature	Junction temperatu	re	TJ	-55 to +150	°C			
Storage temperature			T _{STG}	-55 to +150	°C			

The GLxxT contains an avalanche diode (pin 3-1) and a switching diode (pin 3-2). With pin 1 connected to the signal or data line and pin 2 connected to ground both diodes are in series (pin 3 remains unconnected). The big and robust avalanche diode, driven in reverse direction, provides the working range V_{RWM} of 5 V, 12 V, 15 V or 24 V. Due to its size the capacitance of the avalanche diode is in the range of typ. 260 pF (GL05T) and 65 pF (GL24T). The small switching diode in series has a low capacitance of just 2.5 pF (typ.). As both diodes are in series (with pin 3 not connected) the total capacitance of both diodes measured between pin 1 and 2 is as low as the capacitance of the switching diode.

Before the GLxxT can provide this low capacitance the big capacitance of the avalanche diode has to be charged up with the first signal or data pulses. This is usually no problem for digital signals like USB or other data ports.

With the GLxxT a signal or data line can be protected against positive transients only. For negative transients another GLxxT can be used to provide a back path for the negative transients as well.



GL05T to GL24T

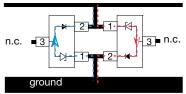
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Data line

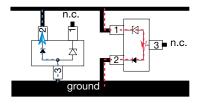
Uni
Unidirectional clamping
performance for positive
transients only.

Data line



BiSy
Bidirectional and Symmetrical
clamping performance for positive
and negative transients.

Data line



BiAs
Bidirectional and Asymmetrical
clamping performance for positive
and negative transients.

ELECTRICAL CHARACTERISTICS GL05T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines	
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5	V	
Reverse voltage	at I _R = 20 μA	V _R	5	-	-	V	
Reverse current	at V _R = 5 V	I _R	-	-	20	μΑ	
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.9	7.5	8.0	V	
Davaras alamaina valtaga	at I _{PP} = 1 A	W	-	-	9.8	V	
Reverse clamping voltage	at I _{PP} = 5 A	V _C	-	-	11	V	
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C _D	=	2.5	5	pF	

ELECTRICAL CHARACTERISTICS GL12T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	12	V		
Reverse voltage	at I _R = 1 μA	V_{R}	12	-	-	V		
Reverse current	at V _R = 12 V	I _R	-	-	1	μA		
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	13.3	14.3	17.2	V		
Reverse clamping voltage	at I _{PP} = 1 A	V _C	-	-	19	V		
neverse clamping voltage	at I _{PP} = 5 A	v _C	-	-	24	V		
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C_D	-	2.5	5	pF		

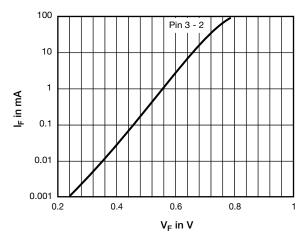
ELECTRICAL CHARACTERISTICS GL15T ($T_{amb} = 25$ °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	15	V		
Reverse voltage	at I _R = 1 μA	V _R	15	-	-	V		
Reverse current	at V _R = 15 V	I _R	-	-	1	μΑ		
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	16.7	17.7	22	V		
Deverse elemning veltage	at I _{PP} = 1 A	V	-	-	24	V		
Reverse clamping voltage	at I _{PP} = 5 A	V _C	-	-	33	V		
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C _D	-	2.5	5	pF		



GL05T to GL24T

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ELECTRICAL CHARACTERISTICS GL24T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N _{channel}	=	-	1	lines			
Reverse stand-off voltage	Max. reverse working voltage	V _{RWM}	=	-	24	V			
Reverse voltage	at I _R = 1 μA	V _R	24	-	-	V			
Reverse current	at V _R = 24 V	I _R	=	-	1	μA			
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	26.7	28.2	33	V			
Payersa alamping valtage	at I _{PP} = 1 A	V	=	-	43	V			
Reverse clamping voltage	at I _{PP} = 5 A	V _C	=	-	55	V			
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C _D	=	2.5	5	pF			



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Fig. 1 - Typical Forward Current I_F vs. Forward Voltage V_F

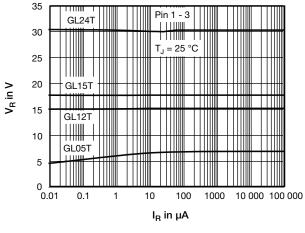


Fig. 3 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

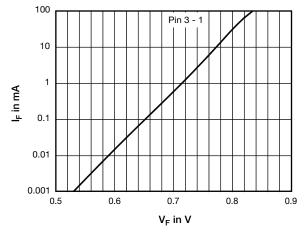


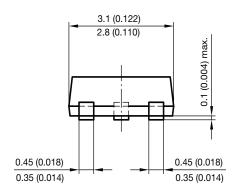
Fig. 2 - Typical Forward Current I_F vs. Forward Voltage V_F

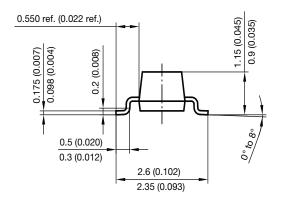


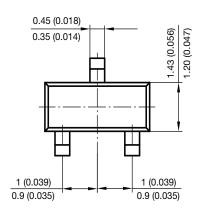
GL05T to GL24T

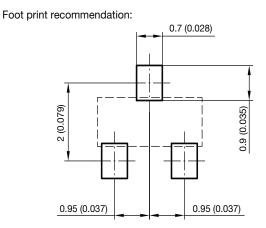
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PACKAGE DIMENSIONS in millimeters (inches): SOT-23

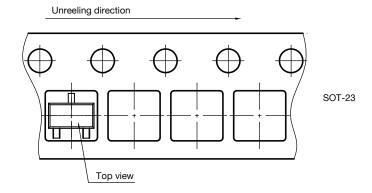








Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23. Sep. 2009



Orientation in carrier tape SOT-23 S8-V-3929.01-006 (4) 04.02.2010 22607



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ESD119B1W01005E6327XTSA1 ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF 3.0SMCJ33CA-F
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